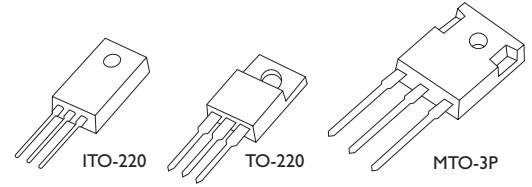


HIGH VOLTAGE • HIGH SPEED SWITCHING TRANSISTORS

HDT series

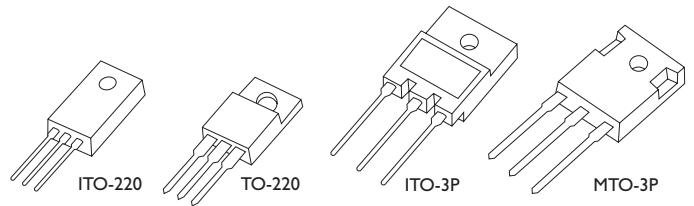
Bipolar transistors (NPN)



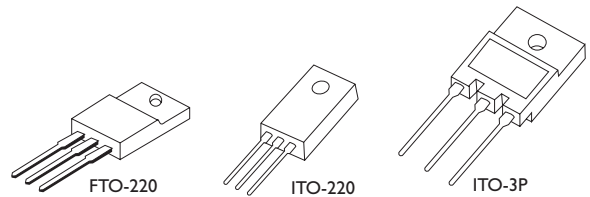
Type No.	Absolute Maximum Ratings								Electrical Characteristics									Outline		
	V _{RM}	V _{CEO}	V _{EBO}	I _C	I _B	P _T	T _{stg}	T _J	V _{CEO} (sus) (min)	h _{FE} (min)	V _{CE} (sat) (max)	V _{BE} (sat) (max)	θ _{JC} (max)	f _T (typ)	t _{on} (max)	t _s (max)	t _f (max)	Package	Figure	
	[V]	[V]	[V]	[A]	[A]	[W]	[°C]	[°C]	[V]	(min)	[V]	[V]	[°C/W]	[MHz]	[μs]	[μs]	[μs]			
2SC4310	900	800	7	6	3	50	-55	150	800	7	1.5	2.5	2.5	7	0.5	3	0.5	TO-220	80-3	
4311						40							3.1					TO-220	82-4	
4312						80							1.56					MTO-3P	86-2	
4313				10	4	100							150							1.25
4314				15	6	130							0.96							

HFX series

Bipolar transistors (NPN)



Type No.	Absolute Maximum Ratings								Electrical Characteristics									Outline															
	V _{RM}	V _{CEO}	V _{EBO}	I _C	I _B	P _T	T _{stg}	T _J	V _{CEO} (sus) (min)	h _{FE} (min)	V _{CE} (sat) (max)	V _{BE} (sat) (max)	θ _{JC} (max)	f _T (typ)	t _{on} (max)	t _s (max)	t _f (max)	Package	Figure														
	[V]	[V]	[V]	[A]	[A]	[W]	[°C]	[°C]	[V]	(min)	[V]	[V]	[°C/W]	[MHz]	[μs]	[μs]	[μs]																
2SC4230	1200	800	7	2	1	50	-55	150	800	8	1	1.5	2.5	8	0.5	3.5	0.3	TO-220	80-3														
4231						30							4.16					ITO-220	82-4														
4232						70							1.7					MTO-3P	86-2														
4233				3	3	100							150					60	150	800	8	1	1.5	1.56	8	0.5	3.5	0.3	MTO-3P	86-2			
4234																		45													2.77	ITO-220	80-3
4235																		80													1.56	ITO-220	82-4
4236				6	3	100							150					1.25	MTO-3P	86-2													
4237				10	4	150							0.83																				
4583				3	1	50							2.5					ITO-3P			88-3												
4584				6	3	65							1.92																				
4585				10	4	85							1.47																				



Switching Transistors for Lighting Equipment

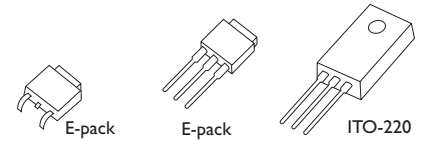
Bipolar transistors (NPN)

Type No.	Absolute Maximum Ratings								Electrical Characteristics									Outline	
	V _{RM}	V _{CEO}	V _{EBO}	I _C	I _B	P _T	T _{stg}	T _J	V _{CEO} (sus) (min)	h _{FE} (min)	V _{CE} (sat) (max)	V _{BE} (sat) (max)	θ _{JC} (max)	f _T (typ)	t _{on} (max)	t _s (max)	t _f (max)	Package	Figure
	[V]	[V]	[V]	[A]	[A]	[W]	[°C]	[°C]	[V]	(min)	[V]	[V]	[°C/W]	[MHz]	[μs]	[μs]	[μs]		
2SC4940	1200	550	7	4	2	30	-55	150	550	10	1	1.5	4.16	10	0.8	3.0	0.3	ITO-220	82-4
4941	1500	800		6	3	65	150		800	15	0.5		1.92	8	0.5	3.5		ITO-3P	88-3
5382	1200	550		9	6	3	40		150	550	10		1	3.13	—	1.3		4.0	FTO-220

LOW SATURATION VOLTAGE SWITCHING TRANSISTORS

LSV series

Bipolar transistors

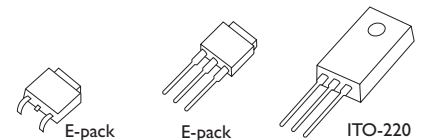


Type No.	Absolute Maximum Ratings								Electrical Characteristics								Outline				
	V _{CBO}	V _{CEO}	V _{EB0}	I _C	I _B	P _T	T _{stg}	T _J	V _{CEO} (sus) (min)	h _{FE} (min)	V _{CE} (sat) (max)	V _{BE} (sat) (max)	θ _{JC} (max)	f _r (typ)	t _{on} (max)	t _s (max)	t _f (max)	Package	Figure		
	[V]	[V]	[V]	[A]	[A]	[W]	[°C]	[°C]	[V]	(min)	[V]	[V]	[°C/W]	[MHz]	[μs]	[μs]	[μs]				
2SA1795	-60	-40	-7	-5	-1.5	10	-55	150	-40	70	-0.3	-1.2	12.5	50	0.3	1.5	0.5	E-pack	*1		
1796				-7		12.5															
1679				-5		5															
1598				-7	25	150							5							ITO-220	82-4
1599				-10	5																
1600				-12	30	4.16															
1601				-15	45	2.77															
2SC4668	60	40	7	7	1.5	10	-55	150	40	70	0.3	1.2	12.5	50	0.3	1.5	0.5	E-pack	*1		
4669				10		12.5															
4148				7		5															
4149				10	25	150							5							ITO-220	82-4
4150				12	5																
4151				15	30	4.16															
4876				30	45	2.78							100								

*1: Leaded package - Fig. 78-3; SMD package - Fig. 77-3

HSV series

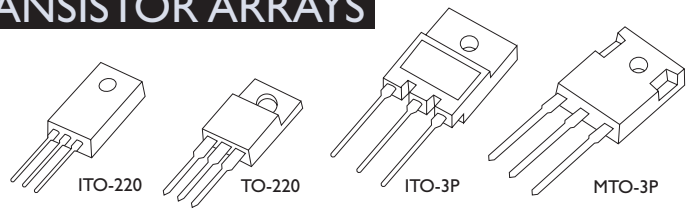
Bipolar transistors



Type No.	Absolute Maximum Ratings								Electrical Characteristics								Outline				
	V _{CBO}	V _{CEO}	V _{EB0}	I _C	I _B	P _T	T _{stg}	T _J	V _{CEO} (sus) (min)	h _{FE} (min)	V _{CE} (sat) (max)	V _{BE} (sat) (max)	θ _{JC} (max)	f _r (typ)	t _{on} (max)	t _s (max)	t _f (max)	Package	Figure		
	[V]	[V]	[V]	[A]	[A]	[W]	[°C]	[°C]	[V]	(min)	[V]	[V]	[°C/W]	[MHz]	[μs]	[μs]	[μs]				
2SA1876	-80	-80	-7	-3	-1.5	10	-55	150	-80	70	-0.3	-1.2	12.5	50	0.3	1.5	0.2	E-pack	*1		
1877				-5		12.5															
1878				-7		5															
1879				-10	25	150							5							ITO-220	82-4
1880				3	1																
2SC4978	100	80	7	3	1.5	10	-55	150	80	70	0.3	1.2	12.5	50	0.3	1.5	0.2	E-pack	*1		
4979				5		12.5															
4980				7		5															
4981				10	25	150							5							ITO-220	82-4
4982				10	5																

*1: Leaded package - Fig. 78-3; SMD package - Fig. 77-3

DARLINGTON TRANSISTORS & TRANSISTOR ARRAYS



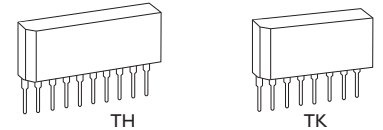
Darlington Power Transistors

Bipolar transistors

Type No.	Absolute Maximum Ratings								Electrical Characteristics								Outline								
	V _{CB0}	V _{CEO}	V _{EB0}	I _C	I _B	P _T	T _{stg}	T _J	V _{CEO} (sus) (min)	h _{FE} (min)	V _{CE} (sat) (max)	V _{BE} (sat) (max)	θ _{jc} (max)	f _r (typ)	t _{on} (max)	t _s (max)	t _f (max)	Package	Figure						
	[V]	[V]	[V]	[A]	[A]	[W]	[°C]	[°C]	[V]	(min)	[V]	[V]	[°C/W]	[MHz]	[μs]	[μs]	[μs]								
2SD1022	100	100	7	5	0.5	30	-55 150	150	—	1500	1.5	2	4.17	20	2	5	3	TO-220	80-3						
1023	200	200														8	5								
1024	100	100	7	8	0.5	50	-55 150	150	—	1500	1.5	2	2.5	20	2	5	3	MTO-3P	86-2						
1025	200	200														8	5								
1026	100	100	7	15	1	100	-55 150	150	—	1500	1.5	2	1.25	20	2	5	3	ITO-3P	88-3						
1027	200	200														8	5								
2196	200	200	7	±4	0.3	25	-55 150	150	—	1500	1.5	2	5.0	20	2	12	5	ITO-220	82-4						
1788	100	100														7	7			0.5	30				
1789	200	200	7	10	0.5	50	-55 150	150	—	1500	1.5	2	2.5	20	2	12	5	ITO-220	82-4						
1790	60 ^{±10}	60 ^{±10}														7	10			0.5	50				
1791	100	100	7	10	0.5	50	-55 150	150	—	1500	1.5	2	2.5	10	2	15	15	ITO-220	82-4						
1792	200	200														7	10			0.5	50				
1793	100	100	7	10	0.5	50	-55 150	150	—	1500	1.5	2	2.5	10	2	15	15	ITO-220	82-4						
1794	200	200														7	10			0.5	50				
1795	500	400	7	10	0.5	50	-55 150	150	—	1500	-1.5	-2	5	20	1	4	2	ITO-220	82-4						
2SB1282	—	—																		7	10	0.5	50		
1283	-100	-100	-7	±4	-0.3	25	-55 150	150	—	1500	-1.5	-2	5	20	1	4	2	ITO-220	82-4						
1284																				—	—	7	10	0.5	50
1285																				—	—	7	10	0.5	50
1448																				—	—	7	10	0.5	50
1448																				—	—	7	10	0.5	50

Transistor Arrays

Bipolar transistors Arrays



Type No.	Absolute Maximum Ratings								Electrical Characteristics							Remarks	Outline	
	V _{CB0}	V _{CEO}	V _{EB0}	I _C	I _B	P _T	T _{stg}	T _J	h _{FE} (min)	V _{CE} (sat) (max)	V _{BE} (sat) (max)	θ _{ja} (max)	t _{on} (max)	t _s (max)	t _f (max)		Package	Figure
	[V]	[V]	[V]	[A]	[A]	[W]	[°C]	[°C]	(min)	[V]	[V]	[°C/W]	[μs]	[μs]	[μs]			
TH3L10	100	100	7	±3	0.3	3.5	-55~150	150	1500	1.5	2	35	2	8	3	NPNX4	TH	65
3L20	200	200																
3C10	±100	±100	7	±3	0.3	3.5	-55~150	150	1500	1.5	2	35	2	8	3	NPNX2, PNPX2	TH	65
3J10	-100	-100																
3L10Z*	60 ^{±10}	60 ^{±10}	7	±3	0.3	3.5	-55~150	150	1500	1.5	2	35	2	8	3	NPNX4	TH	65
5L10	100	100																
5L20	200	200	7	±3	0.3	2.5	-55~150	150	1500	1.5	2	50	2	8	3	NPNX3	TK	66
TK3L10	100	100																
3L20	200	200	7	±3	0.3	2.5	-55~150	150	1500	1.5	2	50	2	8	3	NPNX3	TK	66
3J10	-100	-100																
3L10Z*	60 ^{±10}	60 ^{±10}	7	±3	0.3	2.5	-55~150	150	1500	1.5	2	50	2	8	3	NPNX3	TK	66
5L10	100	100																
5L20	200	200	7	±3	0.3	2.5	-55~150	150	1500	1.5	2	50	2	8	3	NPNX3	TK	66
TK3L10	100	100																
TH5P4	±60	±40	±7	±5	±1.5	3.5	-55~150	150	70	±0.3	±1.2	35.7	0.3	2	0.5	NPNX2, PNPX2	TH	65

*: With zener diode between collector and base

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